

Quad Array for ESD Protection

This quad monolithic silicon voltage suppressor is designed for applications requiring transient overvoltage protection capability. It is intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment, and other applications. Its quad junction common anode design protects four separate lines using only one package. These devices are ideal for situations where board space is at a premium.

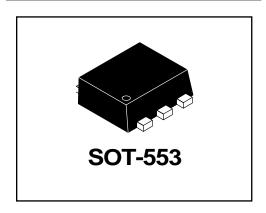
Specification Features

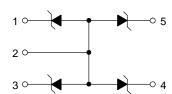
- SOT-553 Package Allows Four Separate Unidirectional Configurations
- Low Leakage < 1 μA @ 3 Volt
- Breakdown Voltage: 5.6 Volt 6.8 Volt @ 1 mA
- ESD Protection Meeting IEC61000-4-2 Level 4
- We declare that the material of product compliance with RoHS requirements.

Mechanical Characteristics

- Void Free, Transfer-Molded, Thermosetting Plastic Case
- Corrosion Resistant Finish, Easily Solderable
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- 100% Lead Free, MSL1 @ 260°C Reflow Temperature

LESDA5V6V5T1G





ORDERING INFORMATION

Device	Package	Shipping	
LESDA5V6V5T1G	SOT-553	3000/Tape & Reel	
LESDA6V2V5T1G	SOT-553	3000/Tape & Reel	
LESDA6V8V5T1G	SOT-553	3000/Tape & Reel	

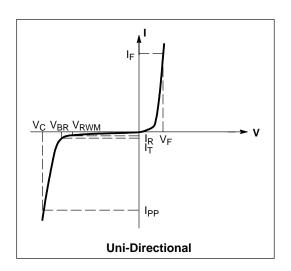


ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter					
I _{PP}	Maximum Reverse Peak Pulse Current					
V _C	Clamping Voltage @ I _{PP}					
V_{RWM}	Working Peak Reverse Voltage					
I _R	Maximum Reverse Leakage Current @ V _{RWM}					
V_{BR}	Breakdown Voltage @ I _T					
I _T	Test Current					
ΘV _{BR}	Maximum Temperature Coefficient of V _{BR}					
l _F	Forward Current					
V _F	Forward Voltage @ I _F					
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}					
I _{ZK}	Reverse Current					
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}					

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MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

	Characteristic	Symbol	Value	Unit
Peak Power Dissipation	on (8 X 20 μs @ T _A = 25°C) (Note 1)	P _{PK}	100	W
Steady State Power -	1 Diode (Note 2)	P _D	300	mW
Thermal Resistance J Above 25°C, Derate		$R_{ hetaJA}$	370 2.7	°C/W mW/°C
Maximum Junction Ter	nperature	T _{Jmax}	150	°C
Operating Junction an	d Storage Temperature Range	T _J T _{stg}	-55 to +150	°C
ESD Discharge	MIL STD 883C - Method 3015-6 IEC1000-4-2, Air Discharge IEC1000-4-2, Contact Discharge	V _{PP}	16 16 9	kV
Lead Solder Temperat	ure (10 seconds duration)	T_L	260	°C

ELECTRICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$

		down Vo	_	Leakage Current		V _C Max @ I _{PP}		Typ Capacitance @ 0 V Bias (Note 3)	Max V _F @ I _F = 200 mA
Device	Min	Nom	Max	V _{RWM}	I _{RWM} (μA)	V _C (V)	I _{PP} (A)	(pF)	(V)
LESDA5V6V5T1G	5.32	5.6	5.88	3.0	1.0	10.5	10	90	1.3
LESDA6V2V5T1G	5.89	6.2	6.51	4.0	0.5	11.5	9.0	80	1.3
LESDA6V8V5T1G	6.46	6.8	7.14	4.3	0.1	12.5	8.0	70	1.3

- Non-repetitive current per Figure 1.
 Only 1 diode under power. For all 4 diodes under power, P_D will be 25%. Mounted on FR-4 board with min pad.
 Capacitance of one diode at f = 1 MHz, V_R = 0 V, T_A = 25°C



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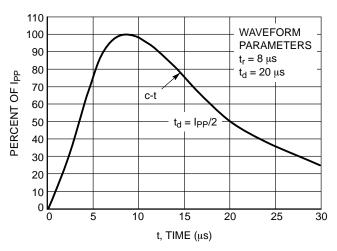


Figure 1. Pulse Waveform

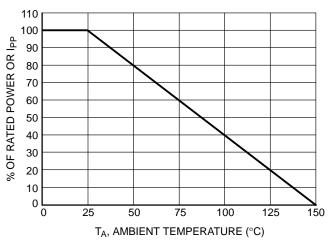


Figure 2. Power Derating Curve

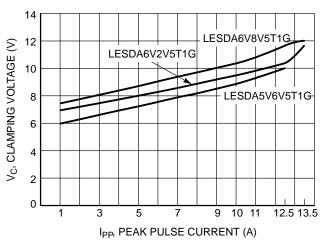


Figure 3. Clamping Voltage versus Peak Pulse Current

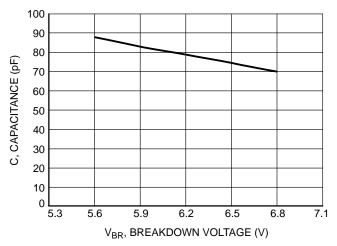


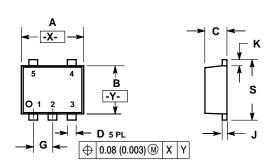
Figure 4. Typical Capacitance



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PACKAGE DIMENSIONS

SOT-553, 5-LEAD



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETERS

 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

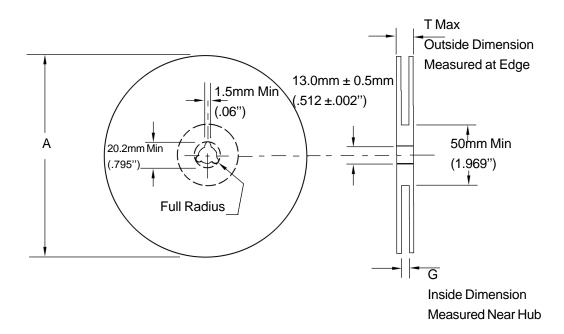
	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.50	1.70	0.059	0.067	
В	1.10	1.30	0.043	0.051	
С	0.50	0.60	0.020	0.024	
D	0.17	0.27	0.007	0.011	
G	0.50	BSC	0.020 BSC		
J	0.08	0.18	0.003	0.007	
K	0.10	0.30	0.004	0.012	
S	1.50	1.70	0.059	0.067	

STYLE 1: PIN 1. BASE 1 2. EMITTER 1/2 3. BASE 2 4. COLLECTOR 2 5. COLLECTOR 1

STYLE 2: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE



EMBOSSED TAPE AND REEL DATA FOR DISCRETES



Size	A Max	G	T Max
8 mm	330mm (12.992")	8.4mm+1.5mm, -0.0 (.33"+.059", -0.00)	14.4mm (.56")

Reel Dimensions

Metric Dimensions Govern — English are in parentheses for reference only

Storage Conditions

Temperature: 5 to 40 Deg.C (20 to 30 Deg. C is preferred)

Humidity: 30 to 80 RH (40 to 60 is preferred)

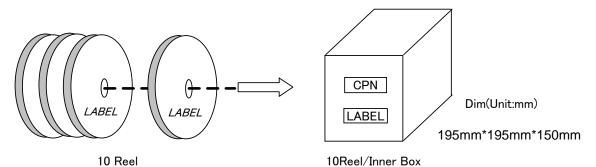
Recommended Period: One year after manufacturing

(This recommended period is for the soldering condition only. The characteristics and reliabilities of the products are not restricted to

this limitation)

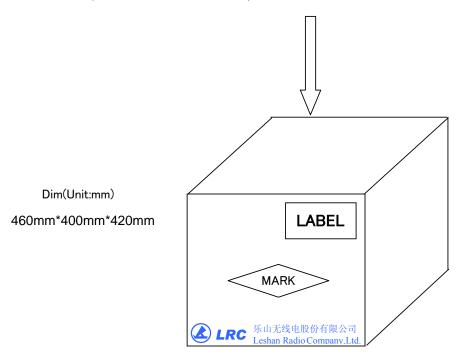


Shipment Specification



3000PCS/Reel 8000PCS/Reel (SOT-723,SOD-723,SOD-923)

30KPCS/Inner Box 80KPCS/Inner Box (SOT-723,SOD-723,SOD-923)



12 Inner Box/Carton

360KPCS/Carton 960KPCS/Carton (SOT-723,SOD-723,SOD-923)